

EL5397C - Preliminary Triple 200MHz Fixed Gain Amplifier

Features

- Gain selectable (+1, -1, +2)
- 200MHz -3dB bandwidth ($A_V = 1$, 2)
- 4mA supply current (per amplifier)
- Single and dual supply operation, from 5V to 10V
- Available in 16-pin QSOP package
- Single (EL5197C) available
- 400MHz, 9mA product available (EL5196C, EL5396C)

Applications

- Battery-powered Equipment
- Hand-held, Portable Devices
- Video Amplifiers
- Cable Drivers
- RGB Amplifiers
- Test Equipment
- Instrumentation
- Current to Voltage Converters

Ordering Information

Part No	Package	Tape & Reel	Outline #
EL5397CS	16-Pin SO	-	MDP0027
EL5397CS-T7	16-Pin SO	7"	MDP0027
EL5397CS-T13	16-Pin SO	13"	MDP0027
EL5397CU	16-Pin QSOP	-	MDP0040
EL5397CU-T13	16-Pin QSOP	13"	MDP0040

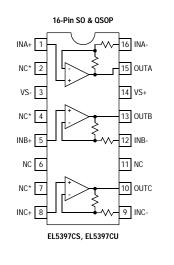
General Description

The EL5397C is a triple channel, fixed gain amplifier with a bandwidth of 200MHz, making these amplifiers ideal for today's high speed video and monitor applications. The EL5397C features integnal gain setting resistors and can be configured in a gain of +1, -1 or +2. The same bandwidth is seen in both gain-of-1 and gain-of-2 applications.

With a supply current of just 4mA per amplifier and the ability to run from a single supply voltage from 5V to 10V, these amplifiers are also ideal for hand held, portable or battery powered equipment.

For applications where board space is critical, the EL5397C is offered in the 16-pin QSOP package, as well as a 16-pin SO. The EL5397C is specified for operation over the full industrial temperature range of -40° C to $+85^{\circ}$ C.

Pin Configurations



* This pin must be left disconnected

Note: All information contained in this data sheet has been carefully checked and is believed to be accurate as of the date of publication; however, this data sheet cannot be a "controlled document". Current revisions, if any, to these specifications are maintained at the factory and are available upon your request. We recommend checking the revision level before finalization of your design documentation.

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Absolute Maximum Ratings (T_A = 25°C)

Values beyond absolute maximum ratings can cause the device to be pre-
maturely damaged. Absolute maximum ratings are stress ratings only
and functional device operation is not implied.Supply Voltage between V_S^+ and V_S^- 11VMaximum Continuous Output Current50mA

Power Dissipation Pin Voltages Storage Temperature Operating Temperature Lead Temperature See Curves V_S- - 0.5V to V_S+ +0.5V -65°C to +150°C -40°C to +85°C 260°C

Important Note:

Operating Junction Temperature

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$.

125°C

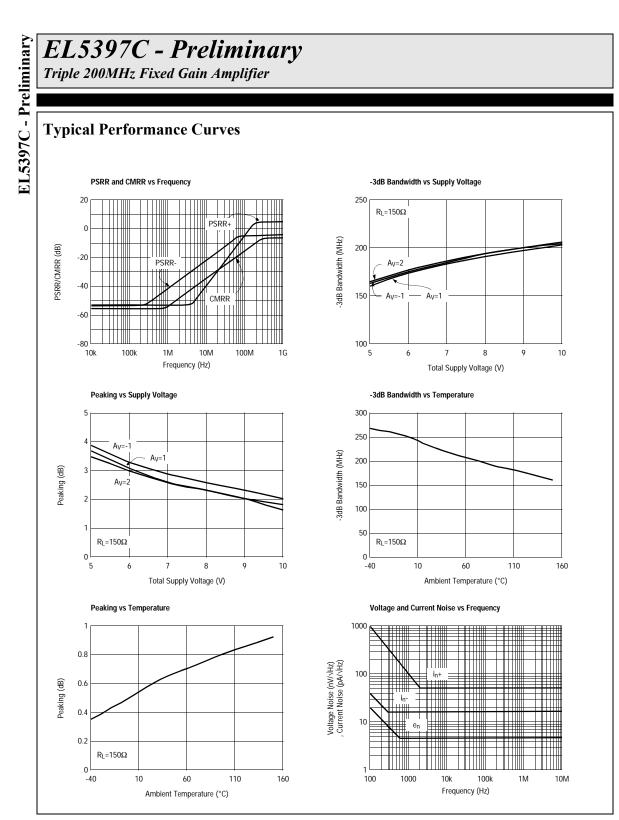
Electrical Characteristics

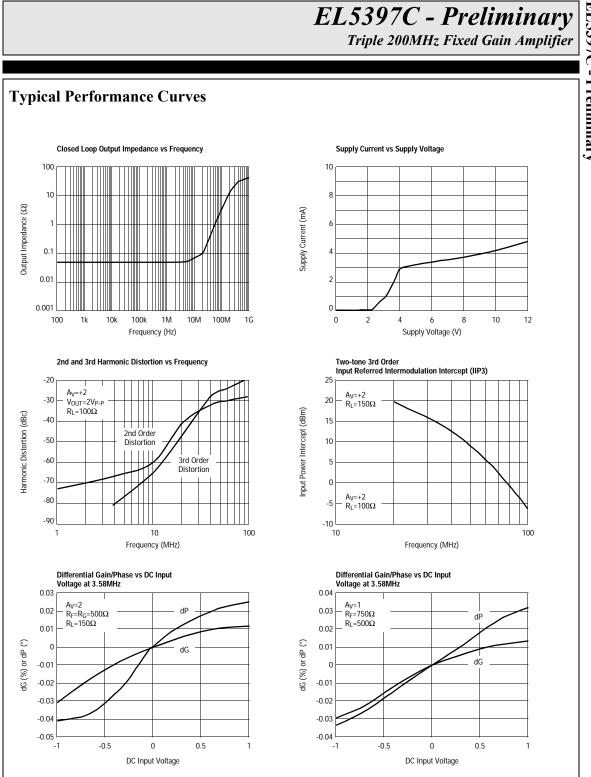
 V_S + = +5V, V_S - = -5V, R_L = 150 Ω , T_A = 25°C unless otherwise specified.

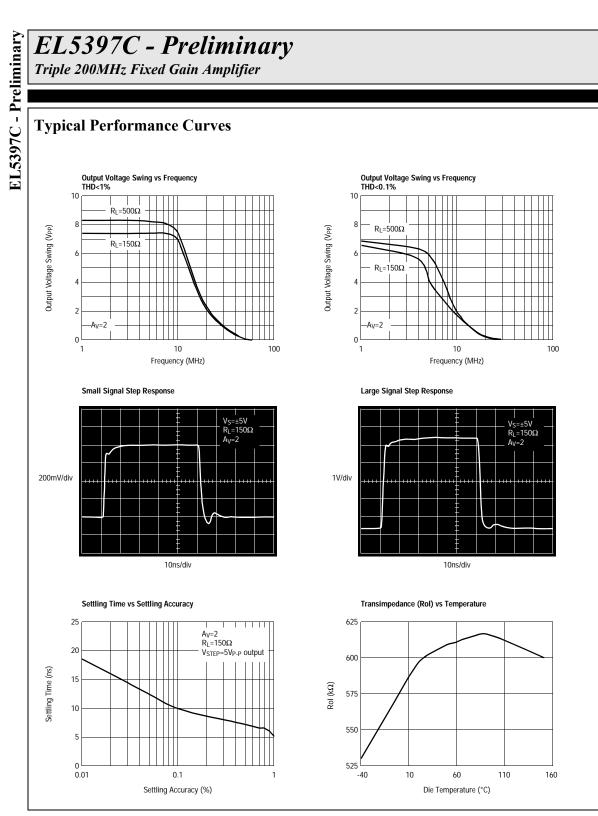
Parameter	Description	Conditions	Min	Тур	Max	Unit
AC Performa	nce					
BW	-3dB Bandwidth	$A_{V} = +1$		200		MHz
		A _V = +2		200		MHz
BW1	0.1dB Bandwidth			20		MHz
SR	Slew Rate	$V_{O} = -2.5V$ to $+2.5V$, $A_{V} = +2$	1900	2100		V/µs
ts	0.1% Settling Time $V_{OUT} = -2.5V$ to $+2.5V$, $AV = -1$			12		ns
Cs	Channel Separation	f = 5MHz		67		dB
en	Input Voltage Noise			4.8		nV/√Hz
in-	IN- input current noise			17		pA/√Hz
in+	IN+ input current noise			50		pA/√Hz
dG	Differential Gain Error ^[1]	A _V = +2		0.03		%
dP	Differential Phase Error ^[1]	$A_{V} = +2$		0.04		٥
DC Performa	nce					
Vos	Offset Voltage		-10	1	10	mV
T _C V _{OS}	Input Offset Voltage Temperature Coefficient	Measured from T _{MIN} to T _{MAX}		5		μV/°C
A _E	Gain Error	$V_0 = -3V$ to $+3V$	-2		2	%
R _F , R _G	Internal R _F and R _G		320	400	480	Ω
Input Charac	teristics					
CMIR	Common Mode Input Range		±3V	±3.3V		V
+I _{IN}	+ Input Current		-60	1	60	μΑ
-I _{IN}	- Input Current		-30	1	30	μΑ
R _{IN}	Input Resistance			45		kΩ
CIN	Input Capacitance			0.5		pF
Output Chara	acteristics					
Vo Output Vol	Output Voltage Swing	$R_L = 150\Omega$ to GND	±3.4V	±3.7V		V
		$R_L = 1K\Omega$ to GND	±3.8V	±4.0V		V
IOUT	Output Current	$R_L = 10\Omega$ to GND	95	120		mA
Supply						
Ison	Supply Current	No Load, VIN = 0V	3	4	5	mA
PSRR	Power Supply Rejection Ratio	DC, $V_S = \pm 4.75V$ to $\pm 5.25V$	55	75		dB
-IPSR	- Input Current Power Supply Rejection	DC, $V_S = \pm 4.75V$ to $\pm 5.25V$	-2		2	μA/V

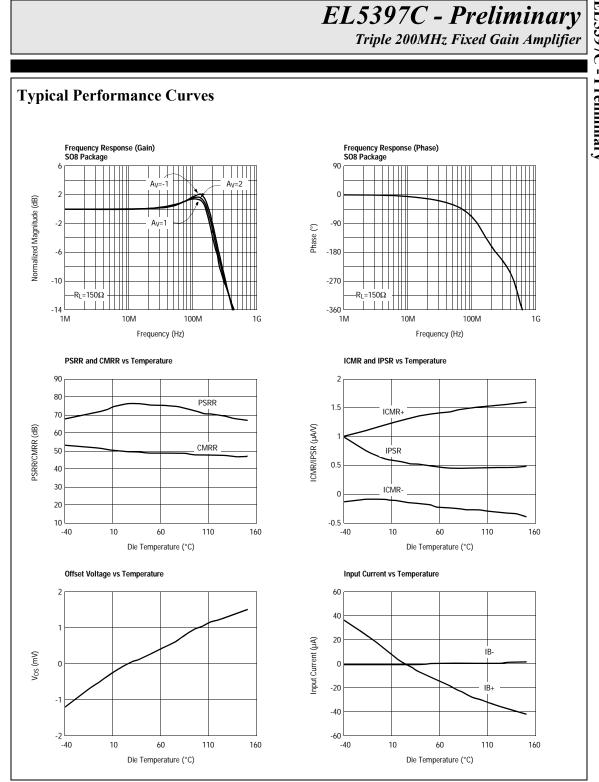
Triple 200MHz Fixed Gain Amplifier **Typical Performance Curves** Frequency Response (Gain) Frequency Response (Phase), All Gains 90 6 Av=-1 Av=2 0 2 Normalized Magnitude (dB) -2 -90 Phase (°) -6 -180 -10 -270 RL=150Ω -R_L=150Ω -14 -360 1M 10M 100M 1G 1M 10M 100M 1G Frequency (Hz) Frequency (Hz) Frequency Response for Various CL Group Delay vs Frequency 14 3.5 _A_V=2 R_L=150Ω 3 Av=2 10 Normalized Magnitude (dB) 2.5 22pF added ÷нш 6 Delay (ns) 2 10pF added 1.5 2 Av: 1 0pF added -2 0.5 $R_L=150\Omega$ -6∟ 1M 0 1M 100M 10M 100M 1G 10M 1G Frequency (Hz) Frequency (Hz) Frequency Response for Various Common-mode Input Voltages Transimpedance (ROL) vs Frequency 10M r m 3V -3V Phase 2 1M Normalized Magnitude (dB) 0٧ -90 Magnitude (Ω) -2 100k Phase (°) 180 10k -6 |-270 Gain -10 1k A_V=2 $-R_L=150\Omega$ -360 11 -14 100 1M 10M 100M 1G -1k 1M 10M 10k 100k 100 1G Frequency (Hz) Frequency (Hz)

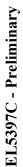
EL5397C - Preliminary



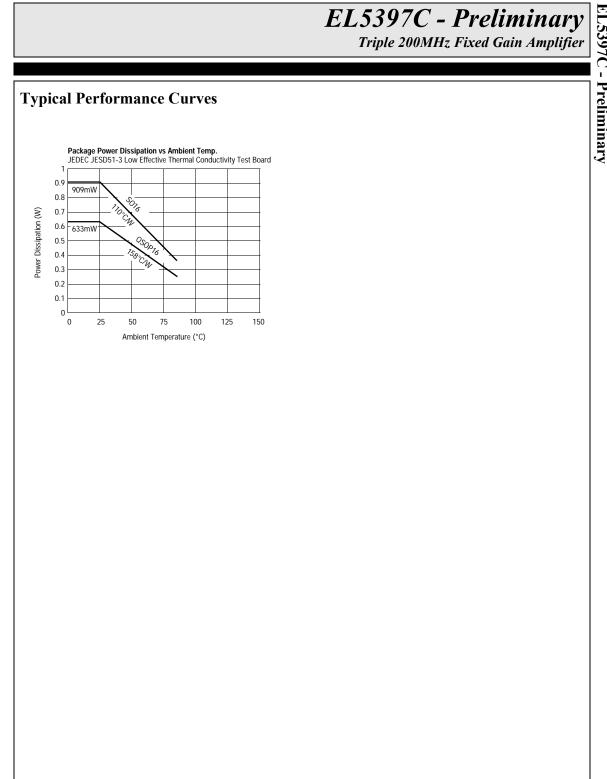








EL5397C - Preliminary Triple 200MHz Fixed Gain Amplifier **Typical Performance Curves** Positive Input Resistance vs Temperature Supply Current vs Temperature 60 50 Supply Current (mA) 40 R_{IN^+} (k Ω) 30 20 10 0 0 -40 10 60 110 160 -40 10 110 160 60 Die Temperature (°C) Die Temperature (°C) Negative Output Swing vs Temperature for Various Loads Positive Output Swing vs Temperature for Various Loads -3.5 4.2 150Ω -3.6 4.1 1kΩ -3.7 Vout (V) -3.8 Vour (V) 3.9 -3.9 3.8 -4 3.7 150Ω 1kΩ -4.1 3.6 -4.2 3.5 -40 10 60 110 160 160 -40 10 60 110 Die Temperature (°C) Die Temperature (°C) Slew Rate vs Temperature **Output Current vs Temperature** 4000 130 Sink 3500 Slew Rate (V/µS) 125 lour (mA) Source 3000 120 $\begin{array}{l} \mathsf{A}_{V}=2\\ \mathsf{R}_{F}=\mathsf{R}_{G}=500\Omega \end{array}$ $R_L=150\Omega$ 2500 115 160 -40 10 60 110 -40 10 60 110 160 Die Temperature (°C) Die Temperature (°C)



EL5396C	ions								
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			Pin Descriptions						
16-Pin SO & 16- Pin QSOP	Pin Name	Function	Equivalent Circuit						
1	INA+	Non-inverting input, Channel A							
2	CEA	Amplifier A enable							
	1/0		Circuit 2						
3 4	VS- CEB	Negative supply Amplifier B enable	(Reference Circuit 2)						
5	INB+	Non-inverting input, Channel B	(Reference Circuit 1)						
6	NC	Not connected							
7	CEC	Amplifier C enable	(Reference Circuit 2)						
8	INC+	Non-inverting input, Channel C	(Reference Circuit 1)						
9	INC-	Inverting input, Channel C	(Reference Circuit 1)						
10	OUTC	Output, Channel C							
			Circuit 3						
11	NC	Not connected							
12	INB-	Inverting input, Channel B	(Reference Circuit 1)						
13	OUTB VS+	Output, Channel B	(Reference Circuit 3)						
14	OUTA	Positive supply Output, Channel A	(Reference Circuit 3)						
16	INA-	Inverting input, Channel A	(Reference Circuit 1)						

EL5397C - Preliminary Triple 200MHz Fixed Gain Amplifier

Applications Information

Product Description

The EL5397C is a current-feedback operational amplifier that offers a wide -3dB bandwidth of 300MHz and a low supply current of 4mA per amplifier. The EL5397C works with supply voltages ranging from a single 5V to 10V and they are also capable of swinging to within 1V of either supply on the output. Because of their currentfeedback topology, the EL5397C does not have the normal gain-bandwidth product associated with voltagefeedback operational amplifiers. Instead, its -3dB bandwidth to remain relatively constant as closed-loop gain is increased. This combination of high bandwidth and low power, together with aggressive pricing make the EL5397C the ideal choice for many low-power/highbandwidth applications such as portable, handheld, or battery-powered equipment.

For varying bandwidth needs, consider the EL5191C with 1GHz on a 9mA supply current or the EL5192C with 600MHz on a 6mA supply current. Versions include single, dual, and triple amp packages with 5-pin SOT23, 16-pin QSOP, and 8-pin or 16-pin SO outlines.

Power Supply Bypassing and Printed Circuit Board Layout

As with any high frequency device, good printed circuit board layout is necessary for optimum performance. Low impedance ground plane construction is essential. Surface mount components are recommended, but if leaded components are used, lead lengths should be as short as possible. The power supply pins must be well bypassed to reduce the risk of oscillation. The combination of a 4.7μ F tantalum capacitor in parallel with a 0.01μ F capacitor has been shown to work well when placed at each supply pin.

For good AC performance, parasitic capacitance should be kept to a minimum, especially at the inverting input. (See the Capacitance at the Inverting Input section) Even when ground plane construction is used, it should be removed from the area near the inverting input to minimize any stray capacitance at that node. Carbon or Metal-Film resistors are acceptable with the Metal-Film resistors giving slightly less peaking and bandwidth because of additional series inductance. Use of sockets, particularly for the SO package, should be avoided if possible. Sockets add parasitic inductance and capacitance which will result in additional peaking and overshoot.

Capacitance at the Inverting Input

Any manufacturer's high-speed voltage- or currentfeedback amplifier can be affected by stray capacitance at the inverting input. For inverting gains, this parasitic capacitance has little effect because the inverting input is a virtual ground, but for non-inverting gains, this capacitance (in conjunction with the feedback and gain resistors) creates a pole in the feedback path of the amplifier. This pole, if low enough in frequency, has the same destabilizing effect as a zero in the forward openloop response. The use of large-value feedback and gain resistors exacerbates the problem by further lowering the pole frequency (increasing the possibility of oscillation.)

The EL5397C has been optimized with a 475Ω feedback resistor. With the high bandwidth of these amplifiers, these resistor values might cause stability problems when combined with parasitic capacitance, thus ground plane is not recommended around the inverting input pin of the amplifier.

Feedback Resistor Values

The EL5397C has been designed and specified at a gain of +2 with R_F approximately 500 Ω . This value of feedback resistor gives 200MHz of -3dB bandwidth at $A_V\!=\!2$ with 2dB of peaking. With $A_V\!=\!-2$, an R_F of approximately 500 Ω gives 175MHz of bandwidth with 0.2dB of peaking. Since the EL5397C is a current-feedback amplifier, it is also possible to change the value of R_F to get more bandwidth. As seen in the curve of Frequency Response for Various R_F and R_G , bandwidth and peaking can be easily modified by varying the value of the feedback resistor.

Because the EL5397C is a current-feedback amplifier, its gain-bandwidth product is not a constant for different closed-loop gains. This feature actually allows the EL5397C to maintain about the same -3dB bandwidth. As gain is increased, bandwidth decreases slightly while

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stability increases. Since the loop stability is improving with higher closed-loop gains, it becomes possible to reduce the value of R_F below the specified 475 Ω and still retain stability, resulting in only a slight loss of bandwidth with increased closed-loop gain.

Supply Voltage Range and Single-Supply Operation

The EL5397C has been designed to operate with supply voltages having a span of greater than 5V and less than 10V. In practical terms, this means that the EL5397C will operate on dual supplies ranging from $\pm 2.5V$ to $\pm 5V$. With single-supply, the EL5397C will operate from 5V to 10V.

As supply voltages continue to decrease, it becomes necessary to provide input and output voltage ranges that can get as close as possible to the supply voltages. The EL5397C has an input range which extends to within 2V of either supply. So, for example, on +5V supplies, the EL5397C has an input range which spans $\pm 3V$. The output range of the EL5397C is also quite large, extending to within 1V of the supply rail. On a $\pm 5V$ supply, the output is therefore capable of swinging from -4V to +4V. Single-supply output range is larger because of the increased negative swing due to the external pull-down resistor to ground.

Video Performance

For good video performance, an amplifier is required to maintain the same output impedance and the same frequency response as DC levels are changed at the output. This is especially difficult when driving a standard video load of 150Ω , because of the change in output current with DC level. Previously, good differential gain could only be achieved by running high idle currents through the output transistors (to reduce variations in output impedance.) These currents were typically comparable to the entire 4mA supply current of each EL5397C amplifier. Special circuitry has been incorporated in the EL5397C to reduce the variation of output impedance with current output. This results in dG and dP specifications of 0.03% and 0.04°, while driving 150 Ω at a gain of 2.

Video performance has also been measured with a 500Ω load at a gain of +1. Under these conditions, the

EL5397C has dG and dP specifications of 0.03% and 0.04°.

Output Drive Capability

In spite of its low 4mA of supply current, the EL5397C is capable of providing a minimum of ± 120 mA of output current. With a minimum of ± 120 mA of output drive, the EL5397C is capable of driving 50 Ω loads to both rails, making it an excellent choice for driving isolation transformers in telecommunications applications.

Driving Cables and Capacitive Loads

When used as a cable driver, double termination is always recommended for reflection-free performance. For those applications, the back-termination series resistor will decouple the EL5397C from the cable and allow extensive capacitive drive. However, other applications may have high capacitive loads without a back-termination resistor. In these applications, a small series resistor (usually between 5 Ω and 50 Ω) can be placed in series with the output to eliminate most peaking. The gain resistor (R_G) can then be chosen to make up for any gain loss which may be created by this additional resistor at the output. In many cases it is also possible to simply increase the value of the feedback resistor (R_F) to reduce the peaking.

Current Limiting

The EL5397C has no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

Power Dissipation

With the high output drive capability of the EL5397C, it is possible to exceed the 150°C Absolute Maximum junction temperature under certain very high load current conditions. Generally speaking when R_L falls below about 25 Ω , it is important to calculate the maximum junction temperature (T_{JMAX}) for the application to determine if power supply voltages, load conditions, or package type need to be modified for the EL5397C to

EL5397C - Preliminary Triple 200MHz Fixed Gain Amplifier

remain in the safe operating area. These parameters are calculated as follows:

 $T_{JMAX} = T_{MAX} + (\theta_{JA} \times n \times PD_{MAX})$

where:

T_{MAX} = Maximum Ambient Temperature

 θ_{JA} = Thermal Resistance of the Package

n = Number of Amplifiers in the Package

 PD_{MAX} = Maximum Power Dissipation of Each Amplifier in the Package

$\ensuremath{\text{PD}_{\text{MAX}}}$ for each amplifier can be calculated as follows:

$$PD_{MAX} = (2 \times V_S \times I_{SMAX}) + \left[(V_S - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_L} \right]$$

where:

V_S = Supply Voltage

 I_{SMAX} = Maximum Supply Current of 1A

V_{OUTMAX} = Maximum Output Voltage (Required)

R_L = Load Resistance

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General Disclaimer

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HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

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